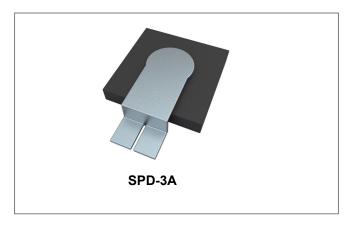


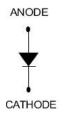




# Power Surface Mount Schottky Rectifier (135V/150V, 120Amp)



## Schematic & Pin Configuration



#### **Features**

- 175 °C T<sub>J</sub> operation
- Low forward voltage drop
- Low reverse leakage current
- · High surge capacities
- · High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- Baseplate: Pure Sn plated; Terminals: Pure Sn plated
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Applications**

- Switching power supply
- Redundant power subsystems
- Reverse battery protection
- Converters
- Many other high current AC/DC power supplies

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.		Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	V <sub>RRM</sub> V <sub>RWM</sub>		135	(129SPC135/A)	V
DC Blocking Voltage	V <sub>RWM</sub> V <sub>R</sub>	-	150	(129SPC150/A)	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @Tc=116°C, rectangular wave form	120		Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	1650		А

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### **Electrical Characteristics:**

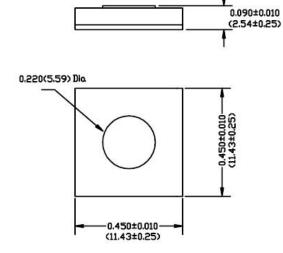
Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V <sub>F1</sub>	@ 120A, Pulse, T <sub>J</sub> = 25 °C	0.82	0.87	V
	V <sub>F2</sub>	@ 120A, Pulse, T <sub>J</sub> = 125 °C	0.67	0.72	V
Reverse Current*	I <sub>R1</sub>	$@V_R = rated V_R, Pulse, T_J = 25 °C$	0.004	3.0	mA
	I <sub>R2</sub>	$@V_R = rated V_R, Pulse, T_J = 125 °C$	0.8	48.0	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz$	2300	3000	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	$T_J$	-	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R <sub>θ</sub> Jc	DC operation	0.20	°C/W

#### **Mechanical Dimensions (Inches/Millimeters)**



0.015 0.105±0.010 (2.67±0.25)

0.040 0.135 (3.43)

0.220(5.59) Dia (3.43)

0.450±0.010 (11.43±0.25)

SPD-3A

## **Suffix "R" Denotes Reversed Polarity**

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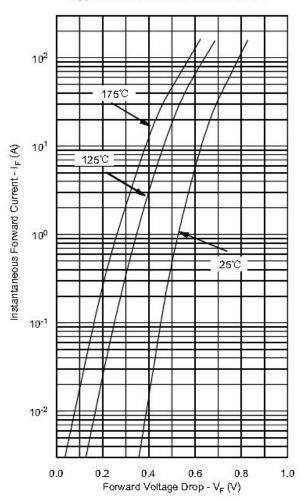




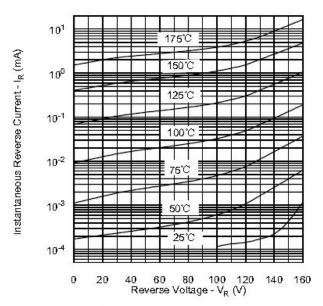


## **Ratings and Characteristics Curves**

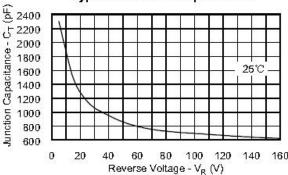




#### Typical Reverse Characteristics







## **Ordering Information**

Device	Package	Shipping	
129SPC135(A)/129SPC150(A)	SPD-3A(Pb-Free)	100pcs/ box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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